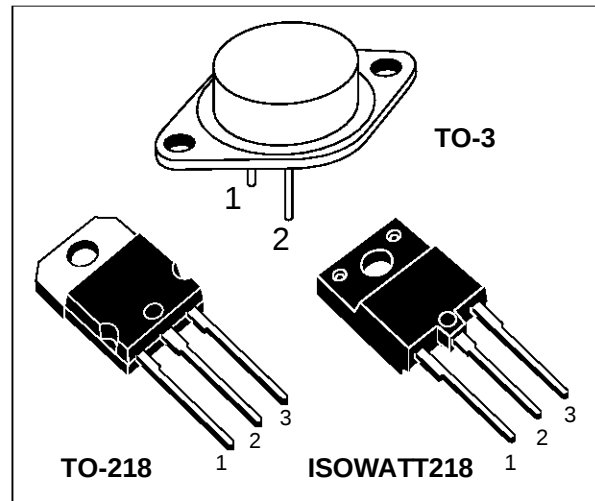


HIGH VOLTAGE IGNITION COIL DRIVER NPN POWER DARLINGTON

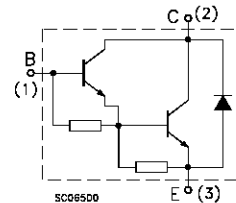
- SGS-THOMSON PREFERRED SALESType
- NPN DARLINGTON
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE
- VERY RUGGED BIPOLAR TECHNOLOGY
- HIGH OPERATING JUNCTION TEMPERATURE
- WIDE RANGE OF PACKAGES

APPLICATIONS

- HIGH RUGGEDNESS ELECTRONIC IGNITIONS



INTERNAL SCHEMATIC DIAGRAM



for TO-3
Emitter: pin 2
Base: pin1
Collector: tab

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value			Unit
		BU941	BU941P	BUB941PFI	
V_{CES}	Collector-Emitter Voltage ($V_{BE} = 0$)	500			V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	400			V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	5			V
I_C	Collector Current	15			A
I_{CM}	Collector Peak Current	30			A
I_B	Base Current	1			A
I_{BM}	Base Peak Current	5			A
P_{tot}	Total Dissipation at $T_c = 25^\circ\text{C}$	180	155	65	W
T_{stg}	Storage Temperature	-65 to 200	-65 to 175	-65 to 175	$^\circ\text{C}$
T_j	Max. Operating Junction Temperature	200	175	175	$^\circ\text{C}$

THERMAL DATA

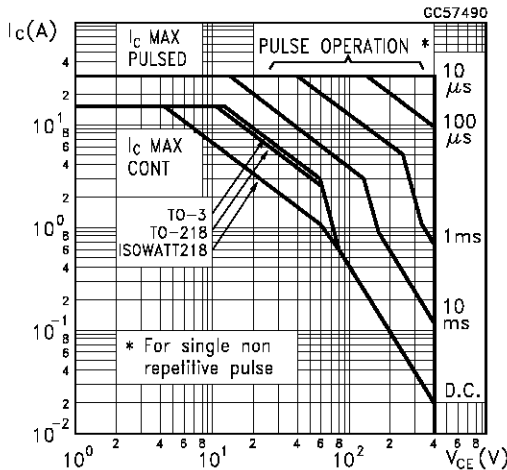
		TO-3	TO-218	ISOWATT218	
$R_{thj-case}$	Thermal Resistance Junction-case Max	0.97	0.97	2.3	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}\text{C}$ unless otherwise specified)

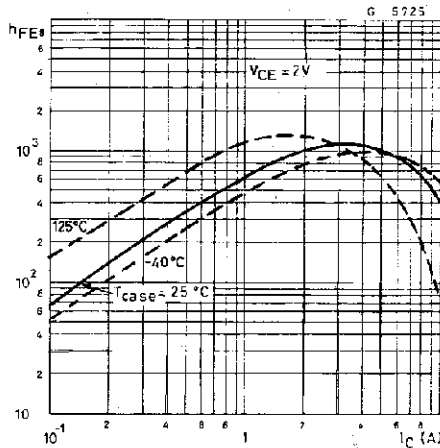
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector Cut-off Current ($V_{BE} = 0$)	$V_{CE} = 500\text{ V}$ $V_{CE} = 500\text{ V}$ $T_j = 125^{\circ}\text{C}$			100 0.5	μA mA
I_{CEO}	Collector Cut-off Current ($I_B = 0$)	$V_{CE} = 450\text{ V}$ $V_{CE} = 450\text{ V}$ $T_j = 125^{\circ}\text{C}$			100 0.5	μA mA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 5\text{ V}$			20	mA
$V_{CEO(sus)}^*$	Collector-Emitter Sustaining Voltage	$I_C = 100\text{ mA}$ $L = 10\text{ mH}$ $I_B = 0$ $V_{CLAMP} = \text{RATED } V_{CEO}$ (See FIG.4)	400			V
$V_{CE(sat)}^*$	Collector-Emitter Saturation Voltage	$I_C = 8\text{ A}$ $I_B = 100\text{ mA}$ $I_C = 10\text{ A}$ $I_B = 250\text{ mA}$ $I_C = 12\text{ A}$ $I_B = 300\text{ mA}$			1.6 1.8 2	V V V
$V_{BE(sat)}^*$	Base-Emitter Saturation Voltage	$I_C = 8\text{ A}$ $I_B = 100\text{ mA}$ $I_C = 10\text{ A}$ $I_B = 250\text{ mA}$ $I_C = 12\text{ A}$ $I_B = 300\text{ mA}$			2.2 2.5 2.7	V V V
h_{FE}^*	DC Current Gain	$I_C = 5\text{ A}$ $V_{CE} = 10\text{ V}$	300			
V_F	Diode Forward Voltage	$I_F = 10\text{ A}$			2.5	V
	Functional Test (see fig. 1)	$V_{CC} = 24\text{ V}$ $V_{clamp} = 400\text{ V}$ $L = 7\text{ mH}$	10			A
t_s t_f	INDUCTIVE LOAD Storage Time Fall Time (see fig. 3)	$V_{CC} = 12\text{ V}$ $V_{clamp} = 300\text{ V}$ $L = 7\text{ mH}$ $I_C = 7\text{ A}$ $I_B = 70\text{ mA}$ $V_{BE} = 0$ $R_{BE} = 47\text{ }\Omega$		15 0.5		μs μs

* Pulsed: Pulse duration = 300 μs , duty cycle 1.5 %

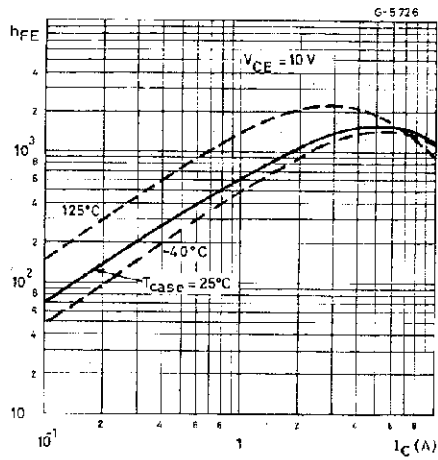
Safe Operating Area



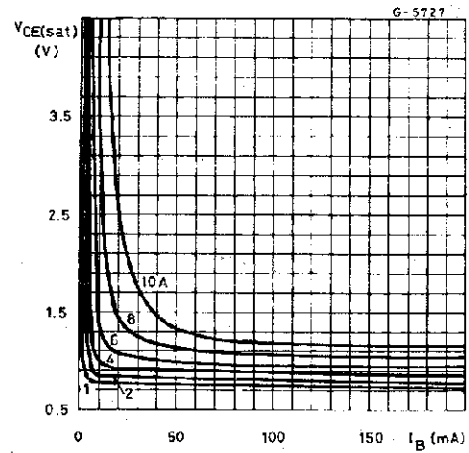
DC Current Gain



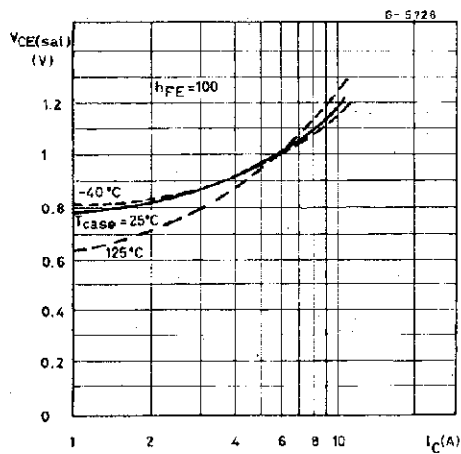
DC Current Gain



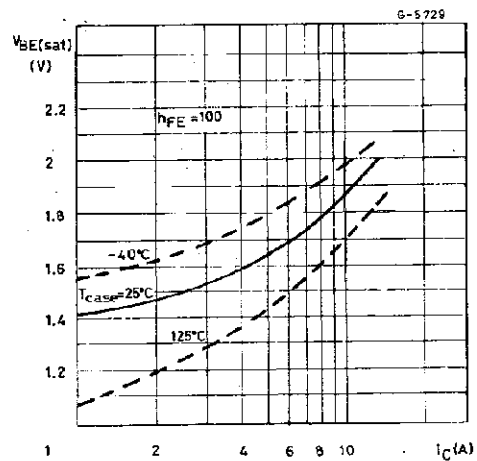
Collector-emitter Saturation Voltage



Collector-emitter Saturation Voltage



Base-emitter Saturation Voltage



Switching Time Inductive Load (see fig.3)

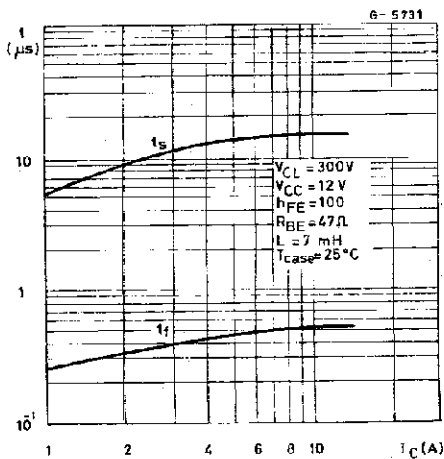


FIGURE 1: Functional Test Circuit

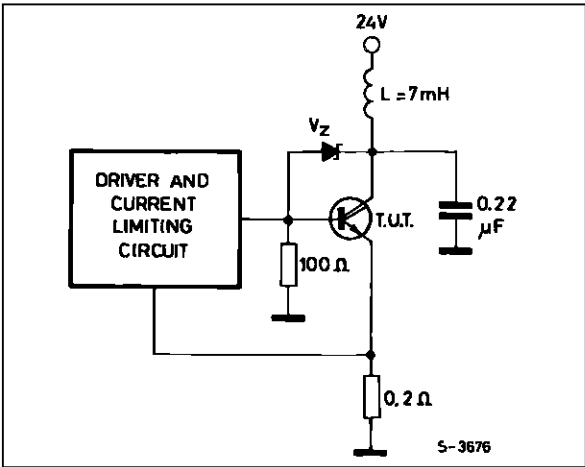


FIGURE 2: Functional Test Waveforms

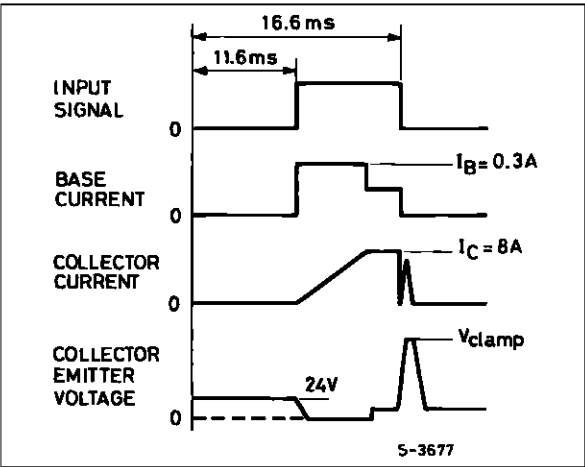


FIGURE 3: Switching Time Test Circuit

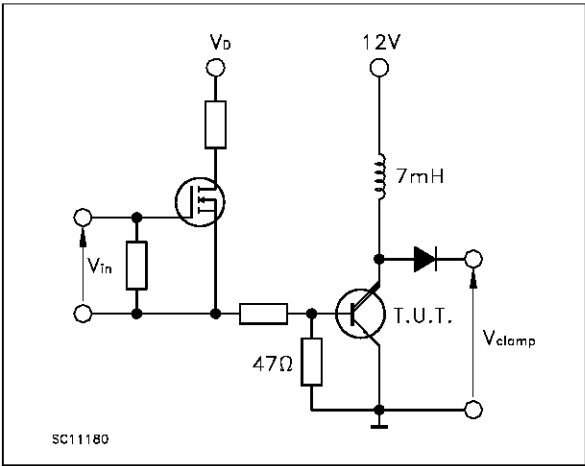
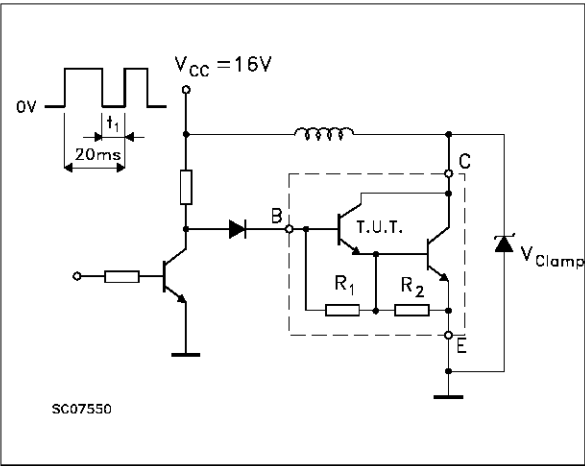
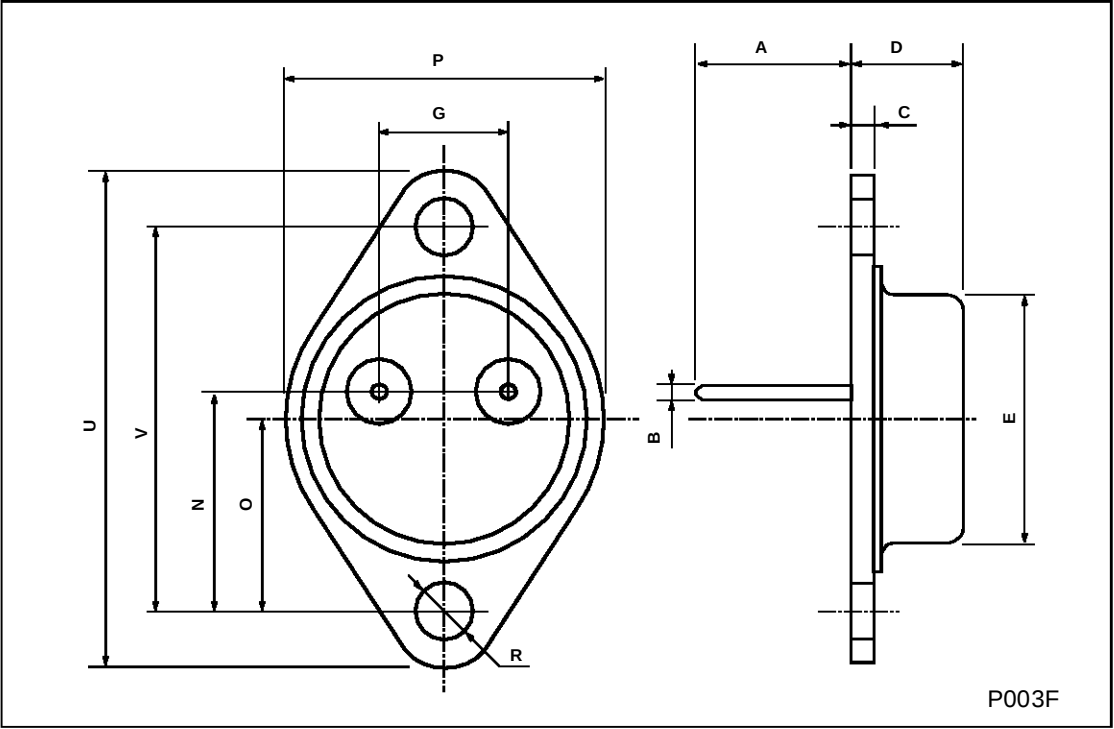


FIGURE 4: Sustaining Voltage Test Circuit



TO-3 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	11.00		13.10	0.433		0.516
B	0.97		1.15	0.038		0.045
C	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		0.351
E	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
N	16.50		17.20	0.649		0.677
P	25.00		26.00	0.984		1.023
R	4.00		4.09	0.157		0.161
U	38.50		39.30	1.515		1.547
V	30.00		30.30	1.187		1.193



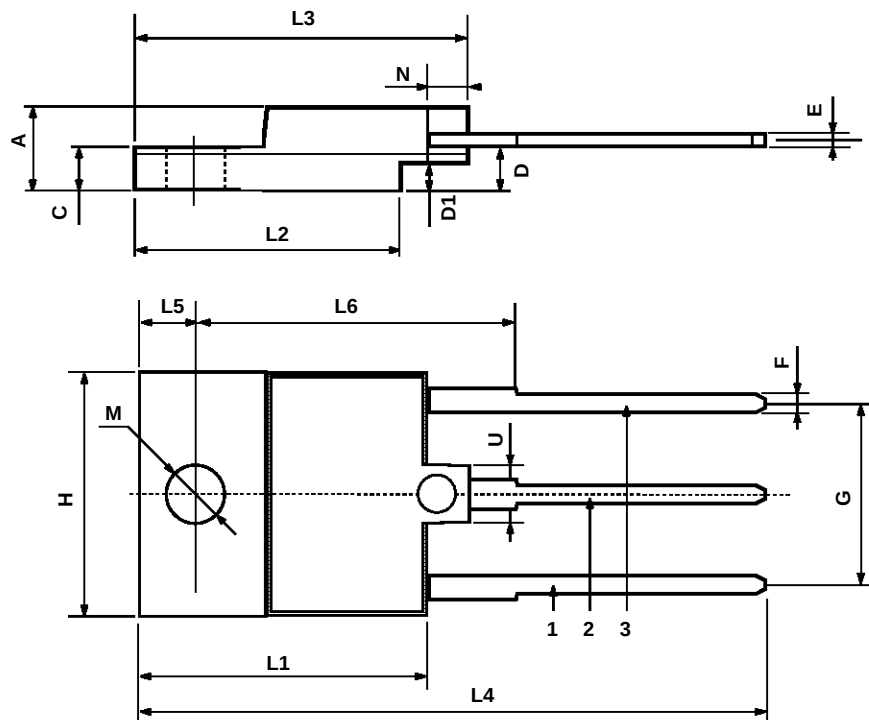
The technical drawing consists of two views of a mechanical component:

- Top View (Front View):** Shows the overall length and width. Dimensions include:
 - A:** Total height.
 - C:** Distance from the left edge to the start of the first rectangular feature.
 - D:** Distance from the end of the last rectangular feature to the right edge.
 - E:** Thickness of the part at the right end.
- Bottom View (Side View):** Shows the profile of the part. Dimensions include:
 - H:** Total height.
 - L5:** Distance from the left edge to the center of the circular hole.
 - L6:** Total length.
 - L3:** Distance from the center of the circular hole to the end of the main body.
 - L2:** Distance from the center of the circular hole to the start of the three parallel features.
 - G:** Total thickness of the three parallel features.
 - R:** Radius of the semi-circular ends.
 - F:** Thickness of the individual parallel features.
 - 1, 2, 3:** Labels pointing to the top surfaces of the three parallel features.

P025A

ISOWATT218 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	5.35		5.65	0.210		0.222
C	3.3		3.8	0.130		0.149
D	2.9		3.1	0.114		0.122
D1	1.88		2.08	0.074		0.081
E	0.75		1	0.029		0.039
F	1.05		1.25	0.041		0.049
G	10.8		11.2	0.425		0.441
H	15.8		16.2	0.622		0.637
L1	20.8		21.2	0.818		0.834
L2	19.1		19.9	0.752		0.783
L3	22.8		23.6	0.897		0.929
L4	40.5		42.5	1.594		1.673
L5	4.85		5.25	0.190		0.206
L6	20.25		20.75	0.797		0.817
M	3.5		3.7	0.137		0.145
N	2.1		2.3	0.082		0.090
U		4.6			0.181	



P025C

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